



# Low Cost, Laser-Trimmered, Precision IC Op Amp

**AD510**

## 1.1 Scope.

This specification covers the detail requirements for a precision laser-trimmed, high accuracy, low drift amplifier.

## 1.2 Part Number.

The complete part number per Table 1 of this specification is as follows:

Device	Part Number
-1	AD510SH/883B

## 1.2.3 Case Outline.

See Appendix 1, of General Specification ADI-M-1000: package outline: H-08A.

## 1.3 Absolute Maximum Ratings. ( $T_A = +25^\circ\text{C}$ unless otherwise noted)

Supply Voltage . . . . .	± 22V
Internal Power Dissipation <sup>1</sup> . . . . .	500mW
Differential Input Voltage . . . . .	± 22V
Input Voltage . . . . .	± 22V
Output Short Circuit Duration . . . . .	Indefinite
Storage Temperature Range . . . . .	-65°C to +150°C
Operating Temperature Range . . . . .	-55°C to +125°C
Lead Temperature Range (Soldering 60sec) . . . . .	+300°C

### NOTE

Note 1: Maximum package power dissipation vs. ambient temperature.

Package Type	MAXIMUM AMBIENT Temperature for Rating	DERATE ABOVE MAXIMUM Ambient Temperature
TO-99	80°C	7.1mW/°C

## 1.5 Thermal Characteristics.

Thermal Resistance  $\theta_{JC} = 65^\circ\text{C/W}$   
 $\theta_{JA} = 150^\circ\text{C/W}$

# AD510 – SPECIFICATIONS

Test	Symbol	Device	Design Limit @ +25°C	Sub Group 1	Sub Group 2, 3	Sub Group 4	Test Condition <sup>1</sup>	Units
Gain Open Loop	A <sub>OL</sub>	- 1	1000	1000	250		V <sub>OUT</sub> = ± 10V	V/mV min
Output Voltage Swing	V <sub>OUT</sub>	- 1	10	10	10		R <sub>L</sub> ≥ 2kΩ	± V min
Output Short Circuit Current	I <sub>SC</sub>	- 1	25	38				+ mA max
Input Offset Voltage	V <sub>OS</sub>	- 1	50			50		± μV max
Input Offset Drift	T <sub>C</sub> V <sub>OS</sub>	- 1	1.0		1.0			± μV/°C max
Input Offset Current	I <sub>OS</sub>	- 1	4.0	4.0	10			± nA max
Input Bias Current	I <sub>B</sub>	- 1	13	13	30			± nA max
Common-Mode Rejection Ratio	CMRR	- 1	110	110	100		V <sub>CM</sub> = ± 10V	dB min
Power Supply Current	I <sub>Q</sub>	- 1	3	3				mA max
Power Supply Rejection Ratio	PSRR	- 1	10	10	20			± μV/V max

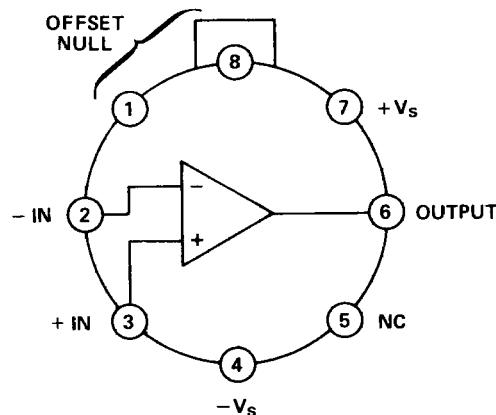
NOTE

<sup>1</sup>T<sub>A</sub> = +25°C, V<sub>S</sub> = ± 15V, unless otherwise noted.

Table 1.

### 3.2.1 Functional Block Diagram and Terminal Assignments.

- Top View



TO-99

### 3.2.4 Microcircuit Technology Group.

This microcircuit is covered by technology group (49).

### 4.2.1 Life Test/Burn-In Circuit.

Steady state life test is per MIL-STD-883 Method 1005. Burn-in is per MIL-STD-883 Method 1015 test condition (B).

